# 2SK3025

# Silicon N-Channel Power F-MOS FET

### ■ Features

- Avalanche energy capacity guaranteed
- High-speed switching
- Low ON-resistance
- No secondary breakdown
- Low-voltage drive
- High electrostatic breakdown voltage

# ■ Applications

- Contactless relay
- Diving circuit for a solenoid
- Driving circuit for a motor
- Control equipment
- Switching power supply

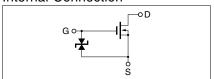
## ■ Absolute Maximum Ratings (T<sub>C</sub> = 25°C)

Parameter		Symbol	Ratings	Unit	
Drain to Source breakdown voltage		V <sub>DSS</sub>	60	V	
Gate to Source voltage		V <sub>GSS</sub>	±20	V	
Drain current	DC	$I_{\mathrm{D}}$	±30	A	
	Pulse	$I_{DP}$	±60	A	
Avalanche energy capacity		EAS*	45	mJ	
Allowable power	$T_C = 25^{\circ}C$	D	20	W	
dissipation	Ta = 25°C	$P_{\rm D}$	1		
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature		$T_{stg}$	-55 to +150	°C	

<sup>\*</sup>  $L = 0.1 \text{mH}, I_L = 30 \text{A}, 1 \text{ pulse}$ 

# unit: mm 6.5±0.1 5.3±0.1 4.35±0.1 0.5±0.1 0.5±0.1 1.2 1.3 0.5±0.1 0.5±0.1 1.3 0.5±0.1 1.

# Internal Connection



## ■ Electrical Characteristics ( $T_C = 25$ °C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	$I_{DSS}$	$V_{DS} = 50V, V_{GS} = 0$			10	μΑ
Gate to Source leakage current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0$			±10	μA
Drain to Source breakdown voltage	$V_{\rm DSS}$	$I_D = 1 \text{mA}, V_{GS} = 0$	60			V
Gate threshold voltage	$V_{th}$	$V_{DS} = 10V, I_D = 1mA$	1		2.5	V
Drain to Source ON-resistance	R <sub>DS(on)1</sub>	$V_{GS} = 10V, I_D = 15A$		25	40	mΩ
	R <sub>DS(on)2</sub>	$V_{GS} = 4V, I_D = 15A$		35	55	mΩ
Forward transfer admittance	Y <sub>fs</sub>	$V_{DS} = 10V, I_{D} = 15A$	9	18		S
Diode forward voltage	$V_{\mathrm{DSF}}$	$I_{DR} = 15A, V_{GS} = 0$			-1.5	V
Input capacitance (Common Source)	C <sub>iss</sub>			1200		pF
Output capacitance (Common Source)	Coss	$V_{DS} = 10V, V_{GS} = 0, f = 1MHz$		400		pF
Reverse transfer capacitance (Common Source)	$C_{rss}$			200		pF
Turn-on time (delay time)	t <sub>d(on)</sub>			10		ns
Rise time	t <sub>r</sub>	$V_{DD} = 30V, I_D = 15A$		20		ns
Fall time	$t_{\rm f}$	$V_{GS} = 10V, R_L = 2\Omega$		140		ns
Turn-off time (delay time)	t <sub>d(off)</sub>			350		ns
Thermal resistance between channel and case	R <sub>th(ch-c)</sub>				6.25	°C/W
Thermal resistance between channel and atmosphere	R <sub>th(ch-a)</sub>				125	°C/W

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